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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/609,470	07/01/2003	Atsushi Yasuno	03500.017390.	1051	
	7590 10/14/200 CELLA HARPER &	EXAMINER			
30 ROCKEFEL	LER PLAZA	STOUFFER, KELLY M			
NEW YORK, NY 10112			ART UNIT	PAPER NUMBER	
			1792		
			MAIL DATE	DELIVERY MODE	
			10/14/2008	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		Appli	cation No.	Applicant(s)	Applicant(s)			
Office Action Summary			09,470	YASUNO, ATSUS	YASUNO, ATSUSHI			
			niner	Art Unit				
		KELL	Y STOUFFER	1792				
Period fo	The MAILING DATE of this commun r Reply	ication appears of	n the cover sheet w	vith the correspondence a	ddress			
WHIC - Exter after - If NO - Failui Any r	ORTENED STATUTORY PERIOD F CHEVER IS LONGER, FROM THE M Isions of time may be available under the provisions SIX (6) MONTHS from the mailing date of this comn period for reply is specified above, the maximum state to reply within the set or extended period for reply eply received by the Office later than three months and patent term adjustment. See 37 CFR 1.704(b).	IAILING DATE OI of 37 CFR 1.136(a). In nunication. atutory period will apply a will, by statute, cause th	F THIS COMMUN no event, however, may a and will expire SIX (6) MO e application to become A	ICATION. reply be timely filed NTHS from the mailing date of this of BANDONED (35 U.S.C. § 133).				
Status								
1) 又	Responsive to communication(s) file	ed on <i>02 Septemb</i>	per 2008					
· · · · · · · · · · · · · · · · · · ·		2b)⊠ This action						
′=		/—		ters prosecution as to th	e merits is			
ا ا	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
	ciocca in accordance with the practi	oo andor Ex parte	, addy,0, 1000 O.I	3. 11, 100 0.0. 210.				
Dispositi	on of Claims							
4)🛛)⊠ Claim(s) <u>1-12 and 14</u> is/are pending in the application.							
	4a) Of the above claim(s) is/are withdrawn from consideration.							
	i) Claim(s) is/are allowed.							
·	6)⊠ Claim(s) <u>1-12 and 14</u> is/are rejected.							
	Claim(s) is/are objected to.							
•	Claim(s) are subject to restrict	tion and/or electi	on requirement.					
	on Papers		•					
•	The specification is objected to by the			– .				
10)	The drawing(s) filed on is/are:	•	· -					
	Applicant may not request that any obje	_		, ,				
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority u	ınder 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some coll None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 								
2) Notic 3) Inforr	t(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (F nation Disclosure Statement(s) (PTO/SB/08) r No(s)/Mail Date	PTO-948)	Paper No	Summary (PTO-413) (s)/Mail Date Informal Patent Application 				

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after allowance or after an Office action under *Ex Parte Quayle*, 25 USPQ 74, 453 O.G. 213 (Comm'r Pat. 1935). Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, prosecution in this application has been reopened pursuant to 37 CFR 1.114. Applicant's submission filed on 12 September 2008 has been entered.

Response to Arguments

Applicant's arguments filed 12 September 2008 have been fully considered but they are not persuasive.

The applicant argues that Moleshi uses a plurality of discharge means in its invention and not two RF electrodes attached to a power source claimed. While it is true that in some instances Moleshi does use different discharge means throughout the document, Moleshi also discloses the use of RF power sources in addition to the chuck that acts as an electrode attached to an RF power source (column 13 lines 7-17), the microwave cavities of the invention (of which there are two or more) may also be RF induction discharge tubes, also RF energy sources which by definition are known to come from electrodes attached to RF energy sources (see column 13 lines 55-60 and

column 14 lines 30-40). In addition, it would be obvious to include at least two RF energy sources, as different powers of RF energy perform different functions in Moleshi (see column 15 lines 27-67.

Further, because the rejection of the claims is under Moleshi in view of Chan, Chan teaches a plurality of RF sources, or electrodes, that are attached to the RF power source and matching network as partially described in the abstract and shown in the figures of Chan. One cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See *In re Keller*, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); *In re Merck & Co.*, 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986).

The applicant argues that Chan uses different plasmas to form different layers, not plural electrodes to form the same layer. One cannot show nonobviousness by attacking references individually where the rejections are based on combinations of references. See *In re Keller*, 642 F.2d 413, 208 USPQ 871 (CCPA 1981); *In re Merck & Co.*, 800 F.2d 1091, 231 USPQ 375 (Fed. Cir. 1986). Additionally, the applicant argues that Moleshi or Chen does not teach the specifics of the applicants' process. However, as stated before in previous office actions, Moleshi and Chen do teach the steps as claimed. It seems that the applicant is arguing for limitations not present in the claims but present in the disclosure, especially when suggesting that Moleshi did not solve the problem of the applicant's disclosure. Although the claims are interpreted in light of the specification, limitations from the specification are not read into the claims. See *In re Van Geuns*, 988 F.2d 1181, 26 USPQ2d 1057 (Fed. Cir. 1993).

Therefore, for at least these reasons, the rejections of the previous office action are maintained and repeated here. New grounds of rejection are present due to amendments.

Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 1-12 and 14 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. Claims 1-4 recite that the two layers of a film are identical, but fails to indicate what about the films are identical. The claim further indicates that the conductivities are the same, are the layers meant to be identical with respect to conductivity as clarified in the claim, composition, stoichiometry, amount of dopant, etc.? Thus this term renders the claims indefinite.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

The factual inquiries set forth in *Graham* **v.** *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:

- 1. Determining the scope and contents of the prior art.
- 2. Ascertaining the differences between the prior art and the claims at issue.

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- 3. Resolving the level of ordinary skill in the pertinent art.
- 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.

Claims 1-12 and 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Moleshi (US 5273609) in view of Chan (US 5653811).

Regarding claims 1-4, Moleshi includes a film formation process for controlling film formation temperature to overcome thermal stress limitations (column 1 lines 49-55 and column 6 lines 3-21) in which a source gas is fed into a discharge space of a reactor and electric power is applied to generate discharge in the discharge space to decompose the source gas, forming a deposited film on a substrate by switching electric power between a first and second discharge means to form a film with semiconductor layers of the same conductivity (columns 7-8 and 10-11 et seq.) The multi-switch processing apparatus of Moleshi is based upon energy sources (column 8 lines 1-10), and the process activation switch for the switching discharge means may be substrate temperature (column 8 lines 19-25) that operates with a preset temperature at its 'on' state and turns 'off' and switches at a predetermined energy level, or above a preset temperature (column 8 lines 30-55). Clearly Moleshi indicated in these passages that the substrate temperature is increased after exposure to the substrate plasma/various treatments. Moleshi also discloses the use of RF power sources in addition to the

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chuck that acts as an electrode attached to an RF power source (column 13 lines 7-17), the microwave cavities of the invention (of which there are two or more) may also be RF induction discharge tubes, also RF energy sources which by definition are known to come from electrodes attached to RF energy sources (see column 13 lines 55-60 and column 14 lines 30-40). In addition, it would be obvious to include at least two RF energy sources, as different powers of RF energy perform different functions in Moleshi (see column 15 lines 27-67). Various plasmas, as in first and second plasmas, are shown in Moleshi in Figures 6 and 7 as well as Chan as discussed below. Moleshi does not include using a device that has capabilities for moving the substrate through the reactor during film formation to be coated by discharge means disposed within the reactor. Chan teaches using a device that has capabilities for moving the substrate through the reactor during film formation to be coated by discharge means disposed within the reactor in order to sequentially treat more than one substrate and use a plasma source attached to the reactor the produced plasmas from specific gases (column 4 lines 8-31 and Figures 5 and 6). Chan shows two different plasmas from two different sources in Figure 6. Additionally, Chan teaches the plasma sources of its disclosed invention may be used to make plasmas of any size (column 1 lines 40-60). It is therefore obvious that one of ordinary skill in the art could easily apply this invention to a wafer that is belt shaped, as it would be functionally equivalent in Chan and could be used for other, larger applications such as windows. Additionally, it is obvious that since the substrate is moving, any subsequent step after the first in Chan would be performed on a different position of the deposited film. Chan also teaches a plurality of

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RF sources, or electrodes, that are attached to the RF power source and matching network as partially described in the abstract and shown in the figures of Chan.

It would have been obvious to one of ordinary skill in the art at the time of the invention to modify Moleshi to include using a device that has capabilities for moving the substrate through the reactor during film formation to be coated by discharge means disposed within the reactor as taught by Chan in order to sequentially treat more than one substrate and use a plasma source attached to the reactor the produced plasmas from specific gases. The plasma sources are clearly opposite the substrate in the Figures of both Moleshi and Chan.

Regarding claims 5-12, the process of Moleshi uses multiple plasma sources and senses multiple conditions such as temperature, time, voltage, and current which activate switches that turn the plasma source from one to the other (column 4 lines 5-43, column 8 lines 10 – column 12 line 36, and Figure 2).

Regarding claim 14, Chan discloses that distances between sources depend upon the shape and uniformity of the desired plasma (column 3 lines 19-32 and column 4 liens 1-7). Chan additionally teaches that chamber pressure affects power to the plasma sources and plasma density. It would have been obvious to a person having ordinary skill in the art at the time the invention was made to modify Moleshi and Chan to includes the claimed ranges of source distance and pressure, since it has been held that where the general conditions of a claim are disclosed in the prior art, discovering the optimum or workable ranges involves only routine skill in the art absent evidence

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showing criticality for the claimed ranges. *In re Aller*, 220 F.2d 454, 105 USPQ 223 (CCPA 1955).

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to KELLY STOUFFER whose telephone number is (571)272-2668. The examiner can normally be reached on Monday - Thursday 7:00-5:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Timothy Meeks can be reached on (571) 272-1423. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Kelly Stouffer Examiner Art Unit 1792

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kms

/Timothy H Meeks/ Supervisory Patent Examiner, Art Unit 1792